

Substitute for form 1449A/B/PTO INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use as many sheets as necessary)			Complete if Known		
			Application Number	Not Yet Assigned 10/784,785	
			Filing Date	Concurrently Herewith	
			First Named Inventor	Hasan Nejad	
			Art Unit	2818	
			Examiner Name	Not Yet Assigned V. Nguyen	
Sheet	1	of	1	Attorney Docket Number	M4065.0509/P509 BC

U.S. PATENT DOCUMENTS					
Examiner Initials*	Cite No. ¹	Document Number	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Number-Kind Code ² (if known)			
W	AA	US-2000/0012228	8/2001	Perner	
W	AB	US-2001/0038548	11/2001	Perner et al.	

FOREIGN PATENT DOCUMENTS						
Examiner Initials*	Cite No. ¹	Foreign Patent Document	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	T ³
		Country Code ³ -Number ⁴ -Kind Code ⁵ (if known)				

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. ¹ Applicant's unique citation designation number (optional). ² See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 801.04. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached.

NON PATENT LITERATURE DOCUMENTS					VIET Q. NGUYEN PRIMARY EXAMINER
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.			T ²
W	CA	How Magnetic RAM Will Work < http://www.howstuffworks.com/mram2.htm >			
W	CB	MTJ Based MRAM System Design < http://www.aps.org/meet/MAR01/baps/abs/S2550004.html >			
W	CC	Motorola Demonstrates Revolutionary Memory Technology < http://www.apspg.com/press/060100/mram-final.html >			
W	CD	Computing Unplugged < http://www.research.ibm.com/thinkresearch/pages/2001/20010202_mram.shtml >			
W	CE	Magnetic Tunnel Junction Materials for Electronic Applications < http://www.tms.org/pubs/journals/JOM/0006/Slaughter/Slaughter-0006.html >			
W	CF	Magnetoelectronics: Magnetic Tunnel Junctions < http://www.almaden.ibm.com/st/projects/magneto/mtj/ >			

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V. Nguyen

12/6/04

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